

Features

- Surface Mount SMC package
- Standoff Voltage: 12 to 58 volts
- Power Dissipation: 3000 watts
- RoHS compliant*
- AEC-Q101 compliant**

Applications

- Protection of power buses
- Protection of I/O interfaces
- Overvoltage transient protection
- Automotive applications
- Telecom, computer, industrial and consumer electronics applications

SMLJ-Q Transient Voltage Suppressor Diode Series

General Information

Bourns offers Transient Voltage Suppressor Diodes for surge and ESD protection applications, in compact chip package DO-214AB (SMC) size format. The Transient Voltage Suppressor series offers a choice of Working Peak Reverse Voltage from 12 V up to 58 V. Typical fast response times are less than 1.0 picosecond from 0 V to Breakdown Voltage.

Bourns® Chip Diodes conform to JEDEC standards, are easy to handle with standard pick and place equipment and the flat configuration minimizes roll away.

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	Symbol	Value	Unit
Minimum Peak Pulse Power Dissipation (T _P = 1 ms) (Note 1,2)	P _{PK}	3000	Watts
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method) (Note 3)	I _{FSM}	300	Amps
Operating Temperature Range	T _J	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C

1. Non-repetitive current pulse, per Pulse Waveform graph and derated above T_A = 25 °C per Pulse Derating Curve.
2. Mounted on 5.0 mm² (0.03 mm thick) copper pads to each terminal.
3. 8.3 ms Single Sine Wave duty cycle = 4 pulses maximum per minute (unidirectional units only).

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*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

**"Q" part number suffix for automotive and other applications requiring appropriate AEC-Q101 compliance.

Specifications are subject to change without notice.

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Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Unidirectional Device		Bidirectional Device		Breakdown Voltage V _{BR} (Volts)			Working Peak Reverse Voltage	Maximum Reverse Leakage @ V _{RWM}	Maximum Reverse Voltage @ I _{RSM}	Maximum Reverse Surge Current
Part Number	Part Marking	Part Number	Part Marking	Min.	Max.	@ I _T (mA)	V _{RWM} (Volts)	I _R (μA)	V _{RSM} (Volts)	I _{RSM} (Amps)
SMLJ12A-Q	HEEQ	SMLJ12CA-Q	IEEQ	13.3	14.7	1	12	2	19.9	150.60
SMLJ13A-Q	HEGQ	SMLJ13CA-Q	IEGQ	14.4	15.9	1	13	2	21.5	139.40
SMLJ14A-Q	HEKQ	SMLJ14CA-Q	IEKQ	15.6	17.2	1	14	2	23.2	129.40
SMLJ15A-Q	HEMQ	SMLJ15CA-Q	IEMQ	16.7	18.5	1	15	2	24.4	123.00
SMLJ16A-Q	HEPQ	SMLJ16CA-Q	IEPQ	17.8	19.7	1	16	2	26.0	115.40
SMLJ17A-Q	HERQ	SMLJ17CA-Q	IERQ	18.9	20.9	1	17	2	27.6	106.60
SMLJ18A-Q	HETQ	SMLJ18CA-Q	IETQ	20.0	22.1	1	18	2	29.2	102.80
SMLJ20A-Q	HEVQ	SMLJ20CA-Q	IEVQ	22.2	24.5	1	20	2	32.4	92.60
SMLJ22A-Q	HEXQ	SMLJ22CA-Q	IEXQ	24.4	26.9	1	22	2	35.5	84.40
SMLJ24A-Q	HEZQ	SMLJ24CA-Q	IEZQ	26.7	29.5	1	24	2	38.9	77.20
SMLJ26A-Q	HFEQ	SMLJ26CA-Q	IFEQ	28.9	31.9	1	26	2	42.1	71.20
SMLJ28A-Q	HFGQ	SMLJ28CA-Q	IFGQ	31.1	34.4	1	28	2	45.4	66.00
SMLJ30A-Q	HFQK	SMLJ30CA-Q	IFKQ	33.3	36.8	1	30	2	48.4	62.00
SMLJ33A-Q	HFMQ	SMLJ33CA-Q	IFMQ	36.7	40.6	1	33	2	53.3	56.20
SMLJ36A-Q	HFPQ	SMLJ36CA-Q	IFPQ	40.0	44.2	1	36	2	58.1	51.60
SMLJ40A-Q	HFRQ	SMLJ40CA-Q	IFRQ	44.4	49.1	1	40	2	64.5	46.40
SMLJ43A-Q	HFTQ	SMLJ43CA-Q	IFTQ	47.8	52.8	1	43	2	69.4	43.20
SMLJ45A-Q	HFVQ	SMLJ45CA-Q	IFVQ	50.0	55.3	1	45	2	72.7	41.20
SMLJ48A-Q	HFXQ	SMLJ48CA-Q	IFXQ	53.3	58.9	1	48	2	77.4	38.80
SMLJ51A-Q	HFZQ	SMLJ51CA-Q	IFZQ	56.7	62.7	1	51	2	82.4	36.40
SMLJ54A-Q	HGEQ	SMLJ54CA-Q	IGEQ	60.0	66.3	1	54	2	87.1	34.40
SMLJ58A-Q	HGGQ	SMLJ58CA-Q	IGGQ	64.4	71.2	1	58	2	93.6	32.00

Notes:

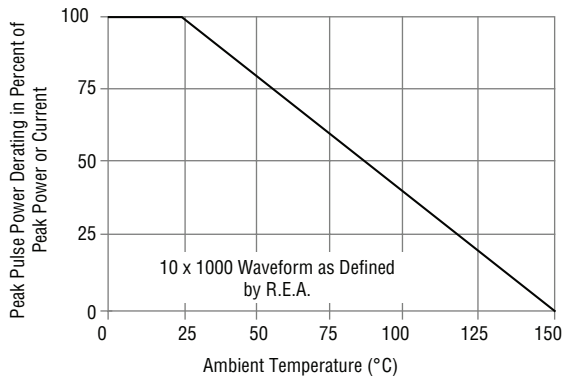
1. Suffix 'A' denotes a 5 % tolerance unidirectional device.
2. Suffix 'CA' denotes a 5 % tolerance bidirectional device.

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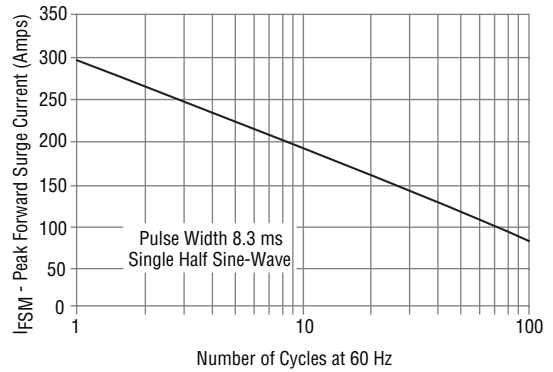
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Performance Graphs

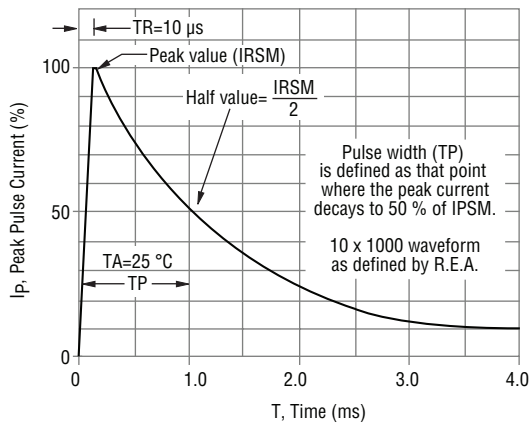
Peak Pulse Power Derating Curve



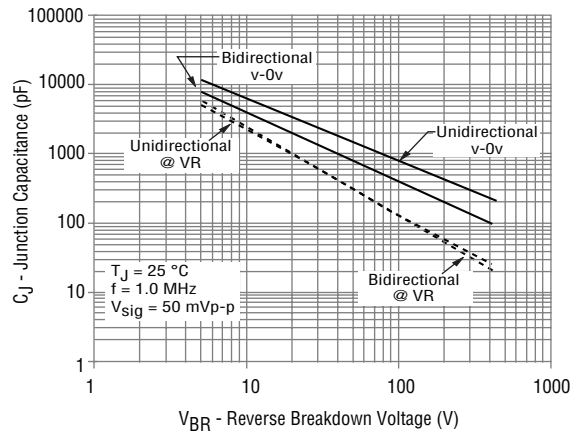
Maximum Non-Repetitive Surge Current



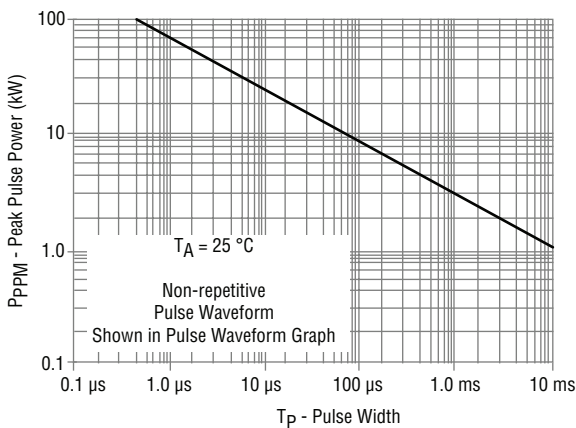
Pulse Waveform



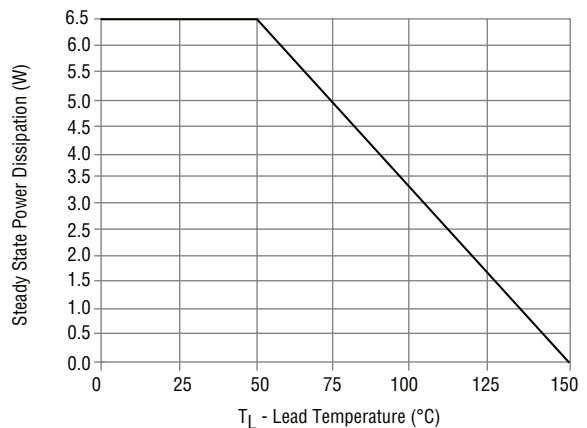
Typical Junction Capacitance



Pulse Rating Curve



Steady State Power Derating Curve



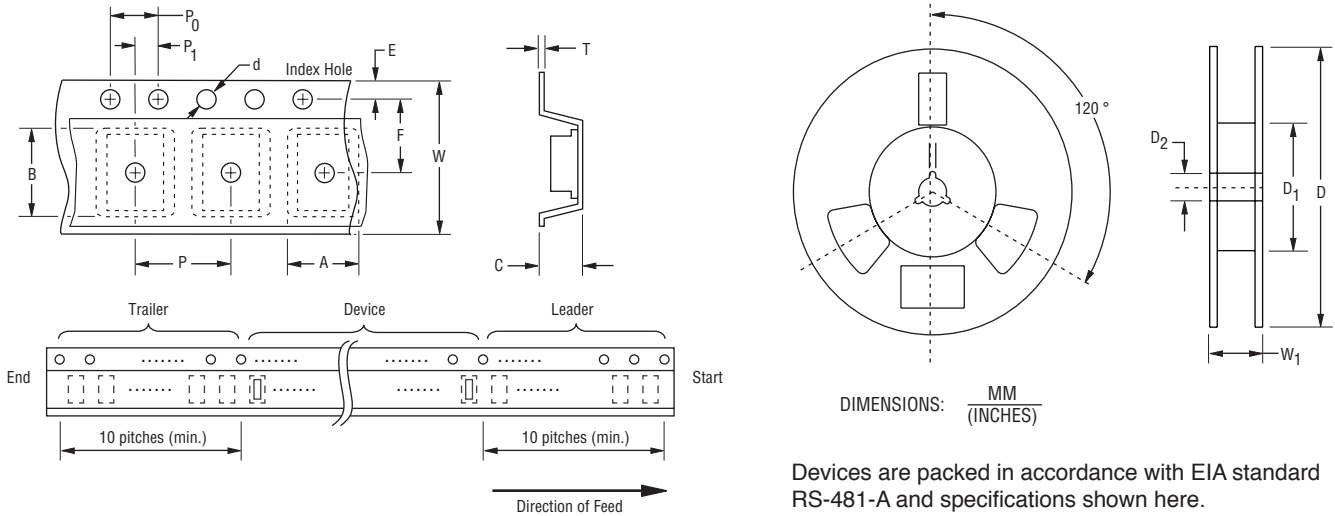
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Packaging Information

The product will be dispensed in tape and reel format (see diagram below).



Devices are packed in accordance with EIA standard RS-481-A and specifications shown here.

Item	Symbol	SMC (DO-214AB)	
		7-Inch Reel	13-Inch Reel
Carrier Width	A	6.0 ± 2.0 (0.236 - 0.079)	
Carrier Length	B	8.3 ± 0.20 (0.327 ± 0.008)	
Carrier Depth	C	2.5 ± 0.20 (0.098 ± 0.008)	
Sprocket Hole	d	1.50 ± 0.10 (0.059 ± 0.004)	
Reel Outside Diameter	D	$\frac{178}{(7.008)}$	$\frac{330}{(12.992)}$
Reel Inner Diameter	D ₁	$\frac{50.0}{(1.969)}$ MIN.	
Feed Hole Diameter	D ₂	$\frac{13.0 + 0.50 / - 0.20}{(0.512 + 0.020 / - 0.008)}$	
Sprocket Hole Position	E	$\frac{1.75 \pm 0.10}{(0.069 \pm 0.004)}$	
Punch Hole Position	F	$\frac{7.50 \pm 0.10}{(0.295 \pm 0.004)}$	
Punch Hole Pitch	P	$\frac{8.00 \pm 0.10}{(0.315 \pm 0.004)}$	
Sprocket Hole Pitch	P ₀	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$	
Embossment Center	P ₁	$\frac{2.00 \pm 0.10}{(0.079 \pm 0.004)}$	
Overall Tape Thickness	T	$\frac{0.30 \pm 0.10}{(0.012 \pm 0.004)}$	
Tape Width	W	$\frac{16.00 \pm 0.30}{(0.630 \pm 0.012)}$	
Reel Width	W ₁	$\frac{22.4}{(0.882)}$ MAX.	
Quantity per Reel	--	500	3000